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Enhanced piezoelectricity and reduced leakage current of a novel (1-x)Bi_{0.5}Na_{0.5}TiO₃-x(Sr_{0.7}Bi_{0.2}□_{0.1})TiO₃ thin film

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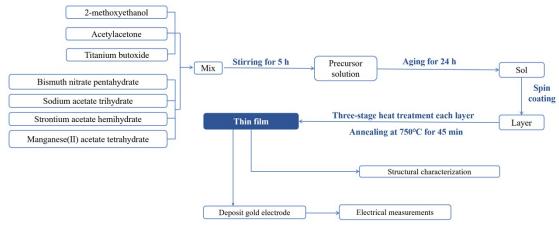


Fig S1 The schematic flow chart for the thin film synthesis

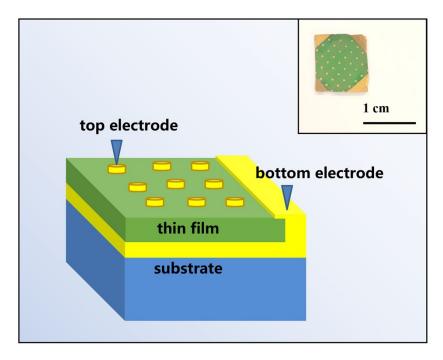


Fig S2 The schematic of the sandwich structure capacitor, the inset shows the real picture of thin film sputtered Au electrode on Pt/Ti/SiO $_2$ /Si substrate

Table S1 The chemicals quantity of all samples

Quantity Samples Chemicals	x = 0.0	x = 0.1	x = 0.2	x = 0.3
C ₃ H ₈ O ₂	9.6074	9.6074	9.6074	9.6074
C ₅ H ₈ O ₂	5.0566	5.0566	5.0566	5.0566
Ti[O(CH ₂) ₃ CH ₃] ₄	8.5950	8.5950	8.5950	8.5950
Bi(NO ₃) ₃ ·5H ₂ O	6.7371	6.3329	5.9286	5.5244
Na(OOCCH ₃)·3H ₂ O	1.8900	1.7010	1.5120	1.3230
Sr(OOCCH ₃) ₂ ·0.5H ₂ O	0.0000	0.3834	0.7669	1.1503
Mn(OOCCH ₃) ₂ ·4H ₂ O	0.0619	0.0619	0.0619	0.0619

100 mL precursor solution (0.25 mol/L)